

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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C2D10120ASilicon Carbide Schottky Diode

ZERO RECOVERY® RECTIFIER

 V_{RRM} = 1200 V $I_{F}(T_{c}=135^{\circ}C) = 14.5 \text{ A}$ Q_{c} = 61 nC

Features

- 1.2kV Schottky Rectifier
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F

Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

Applications

- Switch Mode Power Supplies
- Power Factor Correction
- Motor Drives

Package







TO-220-2



Part Number	Package	Marking
C2D10120A	TO-220-2	C2D10120

Maximum Ratings (T_c=25°C unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions	Note
V _{RRM}	Repetitive Peak Reverse Voltage	1200	V		
V _{RSM}	Surge Peak Reverse Voltage	1200	V		
V _{DC}	DC Blocking Voltage	1200	V		
I _F	Continuous Forward Current	31 14.5 10	А	T _c =25°C T _c =135°C T _c =152°C	
$I_{\sf FRM}$	Repetitive Peak Forward Surge Current	50	А	$T_c=25$ °C, $t_p=10$ ms, Half Sine Wave	
I _{FSM}	Non-Repetitive Peak Forward Surge Current	250	А	T _c =25°C, t _p =10 μs, Pulse	
P _{tot}	Power Dissipation	312 135	W	T _c =25°C T _c =110°C	
$T_{_{\mathtt{J}}}$, $T_{_{\mathtt{stg}}}$	Operating Junction and Storage Temperature	-55 to +175	°C		
	TO-220 Mounting Torque	1 8.8	Nm lbf-in	M3 Screw 6-32 Screw	



Electrical Characteristics

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note
V _F	Forward Voltage	1.6 2.5	1.8 3.0	V	$I_F = 10 \text{ A } T_J = 25^{\circ}\text{C}$ $I_F = 10 \text{ A } T_J = 175^{\circ}\text{C}$	
I_R	Reverse Current	10 20	200 1000	μΑ	$V_R = 1200 \text{ V } T_J = 25^{\circ}\text{C}$ $V_R = 1200 \text{ V } T_J = 150^{\circ}\text{C}$	
Q _c	Total Capacitive Charge	61		nC	$V_R = 1200 \text{ V, } I_F = 10 \text{ A}$ $di/dt = 500 \text{ A/}\mu\text{s}$ $T_J = 25^{\circ}\text{C}$	
С	Total Capacitance	1000 80 59		pF	$V_R = 0 \text{ V, } T_J = 25^{\circ}\text{C, } f = 1 \text{ MHz}$ $V_R = 200 \text{ V, } T_J = 25^{\circ}\text{C, } f = 1 \text{ MHz}$ $V_R = 400 \text{ V, } T_J = 25^{\circ}\text{C, } f = 1 \text{ MHz}$	

Note:

Thermal Characteristics

Symbol	Parameter	Тур.	Unit
$R_{_{ heta JC}}$	Thermal Resistance from Junction to Case	0.48	°C/W

Typical Performance

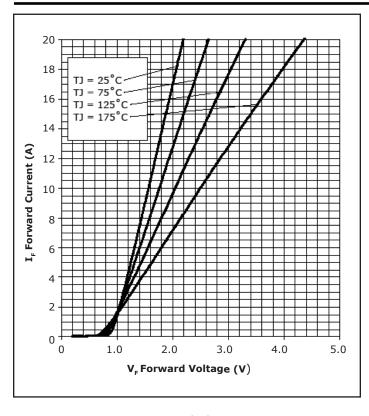


Figure 1. Forward Characteristics

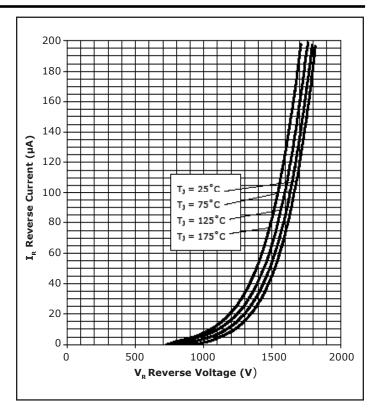
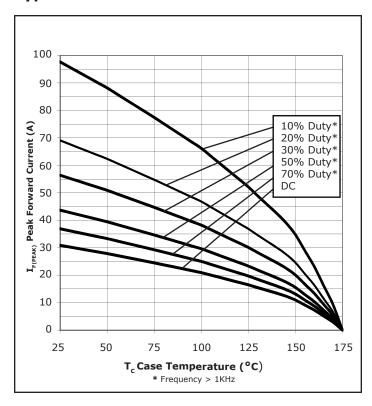


Figure 2. Reverse Characteristics

^{1.} This is a majority carrier diode, so there is no reverse recovery charge.



Typical Performance



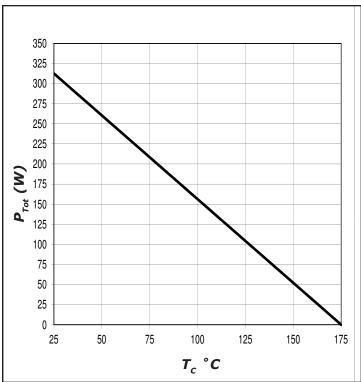


Figure 3. Current Derating

Figure 4. Power Derating

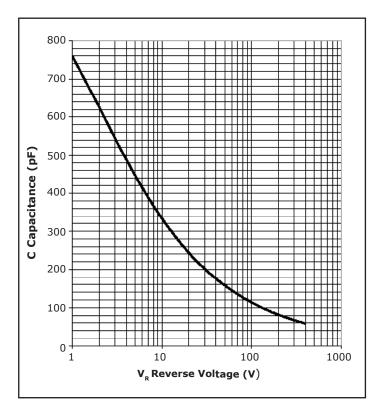


Figure 5. Capacitance vs. Reverse Voltage



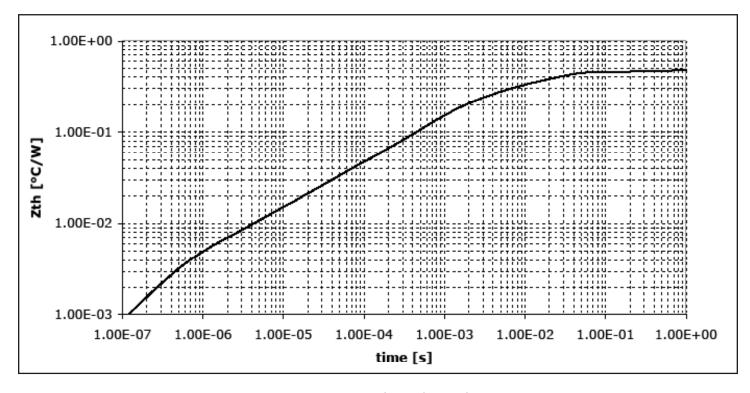


Figure 6. Transient Thermal Impedance

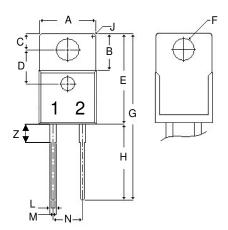


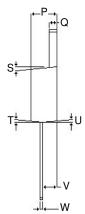
Package Dimensions

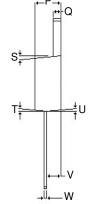
Package TO-220-2

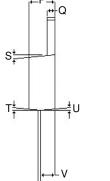
PIN 1O-

PIN 20-











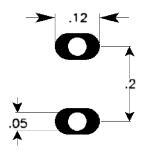
	POS		Millimeters		
	POS	Min	Max	Min	Max
	А	.381	.410	9.677	10.414
	В	.235	.255	5.969	6.477
	С	.100	.120	2.540	3.048
	D	.223	.337	5.664	8.560
	E	.590	.615	14.986	15.621
(F	.143	.153	3.632	3.886
•	G	1.105	1.147	28.067	29.134
	Н	.500	.550	12.700	13.970
	L	.025	.036	.635	.914
	М	.045	.055	1.143	1.397
	N	.195	.205	4.953	5.207
	Р	.165	.185	4.191	4.699
	Q	.048	.054	1.219	1.372
	S	3°	6°	3°	6°
	Т	3°	6°	3°	6°
	U	3°	6°	3°	6°
	V	.094	.110	2.388	2.794
	W	.014	.025	.356	.635
	Х	3°	5.5°	3°	5.5°
	Y	.385	.410	9.779	10.414
	Z	.130	.150	3.302	3.810

NOTE:

1. Dimension L, M, W apply for Solder Dip

Recommended Solder Pad Layout

O CASE



TO-220-2

Part Number	Package	Marking
C2D10120A	TO-220-2	C2D10120

Note: Recommended soldering profiles can be found in the applications note here: http://www.cree.com/power_app_notes/soldering





Notes

• RoHS Compliance

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS2), as implemented January 2, 2013. RoHS Declarations for this product can be obtained from your Cree representative or from the Product Documentation sections of www.cree.com.

• REACh Compliance

REACh substances of high concern (SVHCs) information is available for this product. Since the European Chemical Agency (ECHA) has published notice of their intent to frequently revise the SVHC listing for the foreseeable future, please contact a Cree representative to insure you get the most up-to-date REACh SVHC Declaration. REACh banned substance information (REACh Article 67) is also available upon request.

• This product has not been designed or tested for use in, and is not intended for use in, applications implanted into the human body nor in applications in which failure of the product could lead to death, personal injury or property damage, including but not limited to equipment used in the operation of nuclear facilities, life-support machines, cardiac defibrillators or similar emergency medical equipment, aircraft navigation or communication or control systems, air traffic control systems, or weapons systems.